Zibo Seno Electronic Engineering Co., Ltd.



MBR2040CT – MBR20200CT





20.0A SCHOTTKY BARRIER DIODE

Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

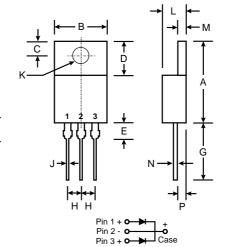
Mechanical Data

Case:TO-220AB, Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: See DiagramMounting Position: Any

Lead Free: For RoHS / Lead Free Version



TO-220AB							
Dim	Min	Max					
Α	14.22	15.88					
В	9.57	10.57					
С	2.54	3.43					
D	5.80	6.80					
E	_	6.35					
G	12.70	14.73					
Н	2.29	2.79					
J	0.51	1.14					
K	3.53Ø	4.14∅					
L	3.56	4.83					
М	1.07	1.47					
N	0.30	0.64					
Р	2.03	2.92					
All Dimensions in mm							

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 2040 CT	MBR 2045 CT	MBR 2050 CT	MBR 2060 CT	MBR 20100 CT	MBR 20150 CT	MBR 20200 CT	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	40	45	50	60	100	150	200	٧
RMS Reverse Voltage	VR(RMS)	28	31	35	42	70	105	140	V
Average Rectified Output Current @T _L = 75°C (Note 1)	lo	20.0						А	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	150					А		
Forward Voltage @I _F = 10A	VFM	0.70 0.80			0.0	35	0.92	V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	lгм	0.1 20						mA	
Typical Junction Capacitance (Note 2)	Cj	350 280 200		200		pF			
Typical Thermal Resistance (Note 1)	R_{θ} JA	3.0 2.0				°C/W			
Operating and Storage Temperature Range	Тj, Tsтg	-55 to +150 -55 to +175			+175	°C			

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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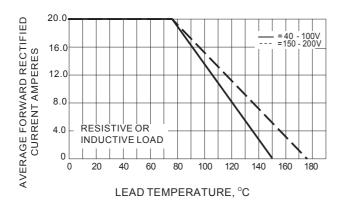


Fig.1- FORWARD CURRENT DERATING CURVE

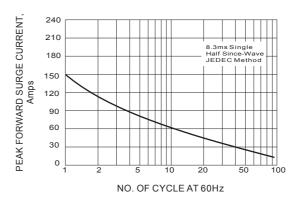


Fig.2- MAXIMUM NON - REPETITIVE SURGE CURRENT

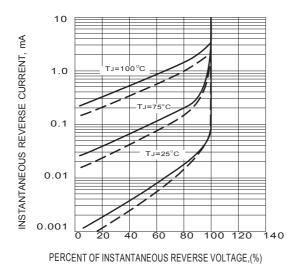


Fig.3- TYPICAL REVERSE CHARACTERISTICS

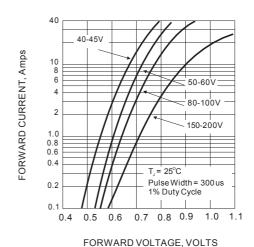


Fig.4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS